Unit in mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

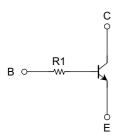
# **RN1710JE**, **RN1711JE**

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Extreme-Super-Mini (5 pin)
- Incorporating a bias resistor into a transistor reduces parts count.

  Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Wide range of resistor values are available to use in various circuit designs.
- Complementary to RN2710JE~2711JE

### **Equivalent Circuit and Bias Resistor Values**



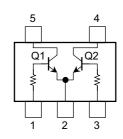
1.0±0.05	1. BASE 1 2. EMITTER 3. BASE 2 4. COLLECTOF 5. COLLECTOF	(B2) (C2) (C1)
JEDEC	_	
EIAJ	_	
TOSHIBA	_	

#### Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	$V_{CEO}$	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	IC	100	mA
Collector power dissipation	P <sub>C</sub> (Note)	100	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

#### Note: Total rating

#### **Equivalent Circuit (top view)**



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can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the
buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and
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damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.

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## Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_{E} = 0$	_	_	100	nA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	100	nA
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	120	_	700	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	$I_C = 5 \text{ mA}, I_B = 0.25 \text{ mA}$	_	0.1	0.3	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA	_	250	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3	6	pF
Input resistor	RN1710JE	R1	_	3.29	4.7	6.11	kΩ
	RN1711JE			7	10	13	K22

Type Name	Marking	
RN1710JE	Type name  XK	
RN1711JE	Type name X M	

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